



Notes for building:

- Q1, Q2, Q3 are all PNP germanium transistors in the original
- If using NPN, use +9V in place of -9V and reverse the polarity of the 50uF and two 5uF electrolytic caps
- Level pot is A100K
- Attack pot is B1K
- Lug 1 of both pots goes to ground
- Lug 2 of Level is Effect Out